

# SANYO Semiconductors DATA SHEET

# EFC4601 — General-Purpose Switching Device Applications

# **Features**

- · 2.5V drive.
- Best suited for LiB charging and discharging switch.
- · Common-drain type.

### **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Source-to-Source Voltage	Vsss		24	V
Gate-to-Source Voltage	VGSS		±12	V
Source Current (DC)	IS		6	Α
Source Current (Pulse)	ISP	PW≤10μs, duty cycle≤1%	40	Α
Total Dissipation	PT	When mounted on ceramic substrate (5000mm²×0.8mm)	1.6	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions		Ratings			Unit
Farameter	Symbol			min	typ	max	Offic
Source-to-Source Breakdown Voltage	V(BR)SSS	IS=1mA, VGS=0V	Test Circuit 1	24			V
Zero-Gate Voltage Source Current	ISSS	VSS=20V, VGS=0V	Test Circuit 1			1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS=±8V, VSS=0V	Test Circuit 2			±10	μΑ
Cutoff Voltage	VGS(off)	VSS=10V, IS=1mA	Test Circuit 3	0.5		1.3	V
Forward Transfer Admittance	yfs	VSS=10V, IS=3A	Test Circuit 4	5	8.5		S
Static Source-to-Source On-State Resistance	Rss(on)1	IS=3A, VGS=4.5V	Test Circuit 5	23.5	34	44	mΩ
	Rss(on)2	IS=3A, VGS=4.0V	Test Circuit 5	25	36	47	mΩ
	Rss(on)3	IS=3A, VGS=3.7V	Test Circuit 5	27	38	49	mΩ
	RSS(on)4	IS=3A, VGS=3.1V	Test Circuit 5	27	42	55	mΩ
	Rss(on)5	IS=3A, VGS=2.5V	Test Circuit 5	30	50	70	mΩ

Marking: FA Continued on next page.

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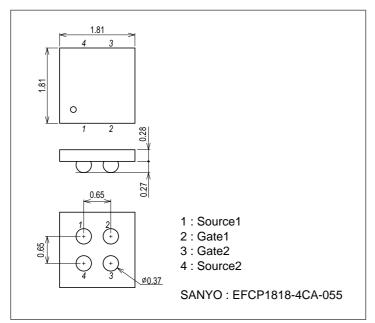
# **EFC4601**

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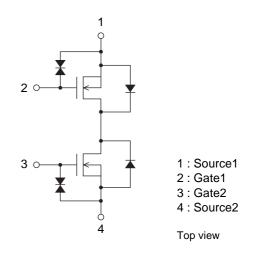
Parameter	Symbol	Conditions		Ratings			Unit
				min	typ	max	Offic
Input Capacitance	Ciss	VSS=10V, f=1MHz	Test Circuit 8		950		pF
Output Capacitance	Coss	V <sub>SS</sub> =10V, f=1MHz	Test Circuit 8		170		pF
Reverse Transfer Capacitance	Crss	V <sub>SS</sub> =10V, f=1MHz	Test Circuit 8		120		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.	Test Circuit 7		20		ns
Rise Time	t <sub>r</sub>	See specified Test Circuit.	Test Circuit 7		185		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit.	Test Circuit 7		54		ns
Fall Time	tf	See specified Test Circuit.	Test Circuit 7		200		ns
Total Gate Charge	Qg	VSS=10V, VGS=10V, IS=6A			8.1		nC
Forward Source-to-Source Voltage	V <sub>F</sub> (S-S)	I <sub>S</sub> =6A, V <sub>GS</sub> =0V	Test Circuit 6		1	1.2	V

# **Package Dimensions**

unit : mm (typ) 7056-001



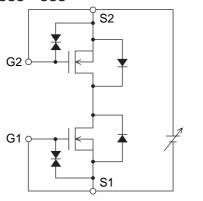
# **Electrical Connection**



IT11565

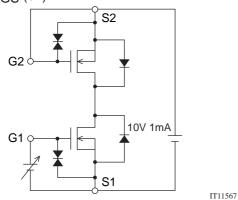
# Test Circuits are example of measuring FET1 side

Test Circuit 1 VSSS / ISSS

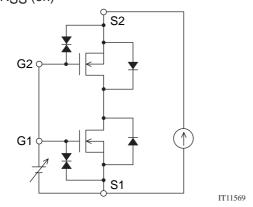


Test Circuit 3

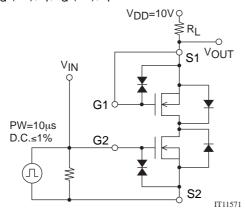
VGS (off)



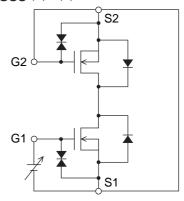
Test Circuit 5 RSS (on)



Test Circuit 7 t<sub>d</sub> (on), t<sub>r</sub>, t<sub>d</sub> (off), t<sub>f</sub>

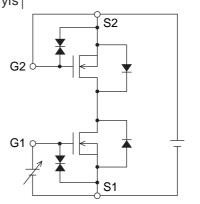


Test Circuit 2 IGSS (+) / (-)



Test Circuit 4





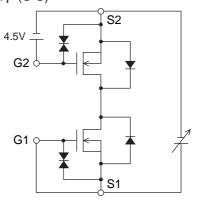
IT11566

IT11568

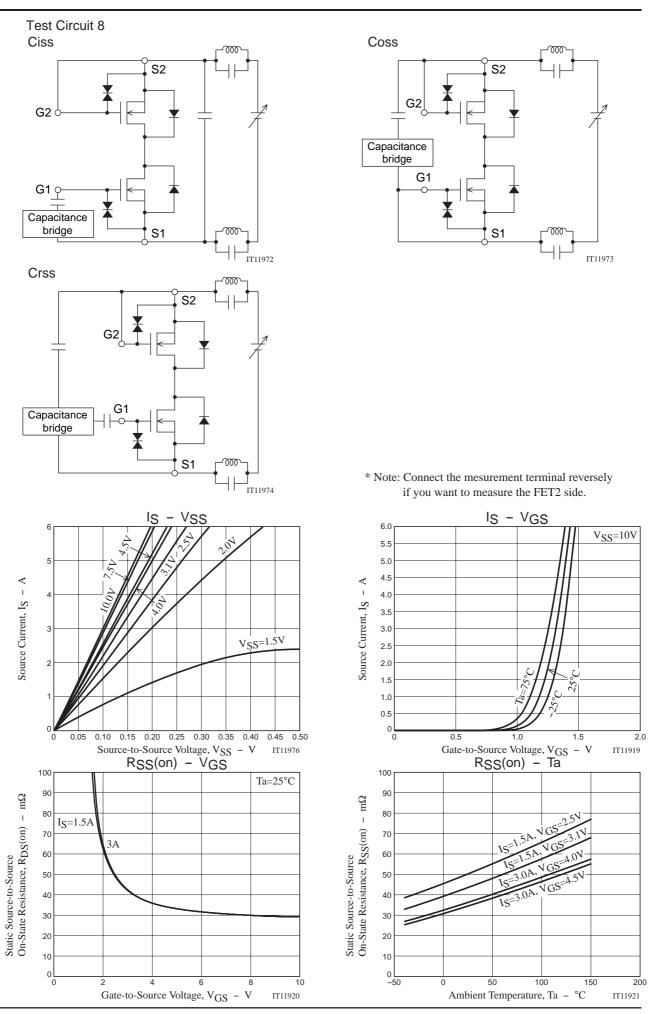
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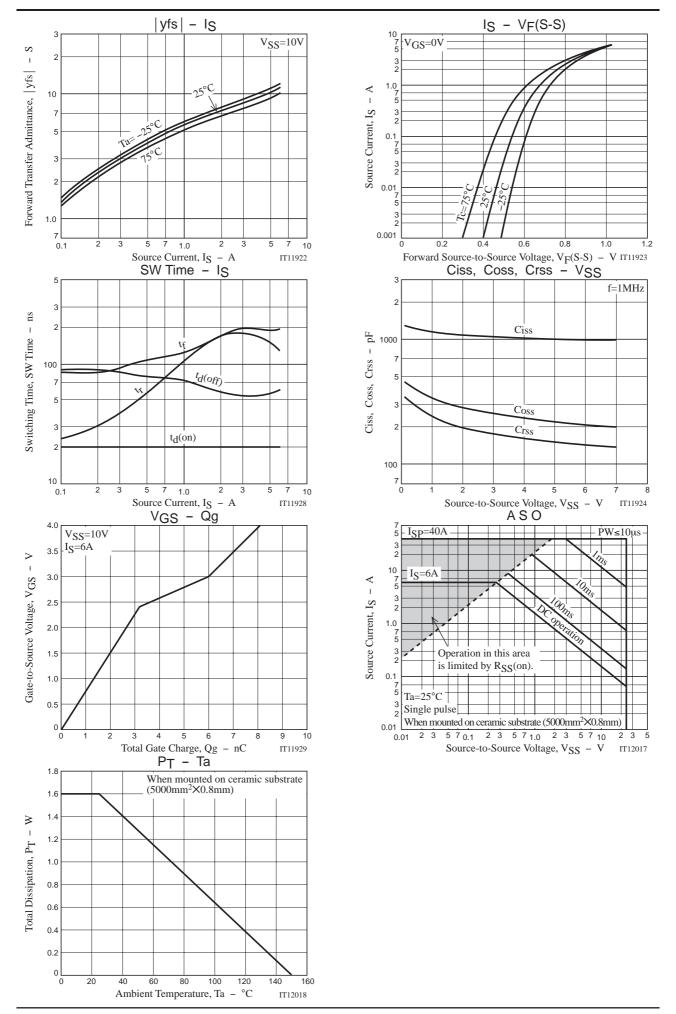
Test Circuit 6

VF (S-S)



<sup>\*</sup> Note: Connect the mesurement terminal reversely if you want to measure the FET2 side.





Note on usage: Since the EFC4601 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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